The Role of Shift Vector in High Harmonic Generation from Non-Centrosymmetric Topological Insulators under Strong Laser Fields

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Abstract

As a promising avenue to obtain new extreme ultraviolet light source and detect electronic properties, high harmonic generation (HHG) has been actively developed both theoretically and experimentally. In solids lacking inversion symmetry, when electrons undergo a nonadiabatic transition, a directional charge shift occurs and is characterized by shift vector, which measures the real-space shift of the photoexcited electron and hole. We have revealed that shift vector plays prominent roles in the three-step model of real-space tunneling mechanism for electrons under strong laser fields. Since shift vector is determined by the topological properties of related wavefunctions, we expect HHG with its contribution can provide direct knowledge on the band topology in noncentrosymmetric topological insulators (TIs). In both Kane-Mele model and realistic material BiTeI, we have found that the shift vector reverses when band inversion happens during the topological phase transition between normal and topological insulators. Under strong laser fields, the reverse of shift vector leads to the sign change of HHG tropisms to the polarization direction of the laser field. This makes HHG a feasible all-optical strong-field method to directly identify the band inversion in non-centrosymmetric TIs.

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I. Introduction

The ultra-fast and intense laser allows manipulation and measurement of atomic-size electron motion on an attosecond time scale [1,2]. A major branch of attosecond science or strong-field physics is the high-harmonic generation (HHG), which can be utilized to achieve isolated attosecond pulses and detect the dynamics of electrons [3-7]. In recent years, the development of solid HHG theory and its experimental applications are in the ascendant. HHG in solids inherits the semi-classical three-step model of gaseous case, including tunnel ionization, free acceleration and forced recollision [8,9]. However, due to the periodic lattice arrangement, dense electron concentration and the macroscopic symmetry of solid-state materials, new phenomena different from HHG in gas phase have been observed, such as the band-gap dependent cut-off energy [10,11], dynamic Bloch oscillation [7,12], abnormal velocity induced by Berry curvature [13-15], and polarization of harmonics caused by symmetry [16,17]. So far, nevertheless, there still be unexplored or unsolved problems that are of interest.

It is universal that the electron transits among energy levels under the irradiation of laser pulses with appropriate frequencies. In the past few years, intensive researches have paid attention to the role of the energy eigenvalue, whilst little to the possible displacement of the electron wave packet during the transition [10,11,18,19]. Most approaches in theory are reasonable for gaseous medium or crystals with inversion symmetry because there is no directional flow of electrons. However, in a solid material lacks inversion symmetry, the electron wave packet tends to shift in a certain direction during the interband transition, and the involved physical process is described by a shift vector, which measures the difference in the center of charge from valence and conduction bands. Previously, the knowledge is limited to the shift current based entirely on the perturbation theory. It is a second-order nonlinear process used to explain the microscopic mechanism of the bulk photovoltaic effect [20-26]. Due to the existence of shift vector in non-centrosymmetric systems, nonperturbative high-harmonic pulse trains (HHPTs) in strong laser fields exhibit a novel physical phenomenon: the burst period of the HHPTs can be modified from half an optical cycle
to a whole single cycle. Herein, we apply this discovery to the non-centrosymmetric topological insulators (TIs), a type of quantum material with large shift vectors [23,26].

As a new class of quantum matter with time reversal symmetry, TIs have exotic characteristics with insulating bulk band and metallic surface state. Their robust surface state is protected by topological invariants of the bulk state and supports quantized spin current against backscattering [27-31]. Therefore, TIs are expected to be applied to dissipationless devices, quantum spintronics and quantum computing [27,30]. It is inspiring that high-order nonlinear optical studies on TIs are continuously progressing, especially for the explorations on topological phase discrimination and electronic dynamics [32-35]. In experiments, an effective method to directly detect topological phase transition is lacking. The topological phases are distinguished experimentally mainly by the topological surface state appeared in the atomic layers on the surface [36,37], whereas the formation of the topological surface state is completely determined by the bulk state. Therefore, it is necessary to trace the root. Substantially, the topological phase transition features band inversion of the bulk state. We claim that it can be recorded by the high-harmonic spectra instead of conventional techniques such as angle-resolved photoemission spectroscopy, and thus propose an experimentally feasible method of using ultrafast and intense lasers to characterize the band inversion in non-centrosymmetric TIs, which is attributed to the reversal of the shift vector.

In this paper, we first use the Kane-Mele (KM) model [28], which is a paragon of the quantum spin Hall effect, to perform semi-classical dynamics analysis and generalized numerical calculations. We then extend the model to a layered polar material BiTeI [23,38] to further confirm the practical significances of our conception. Both the KM model and BiTeI crystal can be controlled to experience the topological phase transition by lattice modulation. By addressing the role of the shift vector in HHG from non-centrosymmetric systems, we are aiming not only to give an improved physical picture of the three-step model, but also to provide an all-optical strong-field method for detecting the topological phase transition in experiments.

II. THEORY
In this work, the theoretical proposals and numerical simulations are based on the semiconductor Bloch equations (SBEs) [39,40] in Houston representation (atomic units are used throughout unless otherwise stated),

\[ i \partial_t \rho_{nm}^k(t) = [\varepsilon_m^k(t) - \varepsilon_n^k(t) - i(1-\delta_{nm})/T_2] \rho_{nm}^k(t) - E(t) \cdot \sum_l [d_{lm}^k(t) \rho_{lm}^k(t) - d_{mli}^k(t) \rho_{ni}^k(t)], \tag{1} \]

which indicates the evolution of electron density \( \rho_{nm}^k \) with time. The time dependent crystal momentum \( k(t) = K + A(t) \) shows the evolution path of electrons in the Brillouin zone (BZ), where \( K \) represents quasi-crystal canonical momentum and \( A(t) \) is the vector potential of the laser field \( E(t) \). \( \varepsilon_n^k \) is the energy of the \( n \)th band at \( k \) and the dephasing time \( T_2 \) is determined by the relaxation time of the system. The dipole matrix elements \( d_{nm}^k(t) = i < u_{n,k} | \nabla_k | u_{m,k} > \) are composed of the periodic part of Bloch wave functions \( | u_{n,k} > \), and can be the adiabatic Berry connections \((n = m)\) or diabatic transition dipole matrix elements \((n \neq m)\).

To understand the role of the shift vector in HHG, we start from interband harmonics under saddle point approximation [18,39,41,42]. In the case of two-bands approximation and considering that only a few of electrons can transit from the valence band to the conduction band, the current parallel to the laser polarization direction in frequency domain can be written as (ignoring the dephasing time)

\[ j_{\text{inter}}(\omega) = \int_{-\infty}^{+\infty} dt \int d^3K \int_{-\infty}^{+\infty} dt' \left| \varepsilon_g^k(t') d_{cv}^{k(t')} \right| \cdot \left| E(t') d_{cv}^{k(t')} \right| e^{-i[s(k,t')-\omega t]} + \text{c.c.}, \tag{2} \]

where \( \varepsilon_g^k = \varepsilon_c^k - \varepsilon_v^k \) is the energy difference between the conduction band \( \varepsilon_c^k \) and valence band \( \varepsilon_v^k \), and the accumulated phase from \( t' \) to \( t \) is

\[ S(k,t,t') = \int_t^{t'} \varepsilon_g^{k(\tau)} d\tau - \int_{k(t')}^{k(t)} [d_{cc}^{k(\tau)} - d_{vv}^{k(\tau)}] d\tau - [\phi_{vc}^{k(t)} + \phi_{cv}^{k(t')}], \tag{3} \]

with \( \phi_{nm}^k \) is the transition dipole phase (TDP) [43]. Taking the saddle point analysis for \( S(k,t,t') - \omega t \),

\[ \partial_t S(k,t,t') = -\varepsilon_g^{k(t')} - E(t') R_{cv}^{k(t')} = 0, \tag{4a} \]
\[
\n\nV_k S(k, t, t') = \int_t^{t'} V_k \varepsilon_g^{k(\tau)} d\tau - R_{cv}^k(t) + R_{cv}^k(t') = 0, \quad (4b)
\]

\[
\n\n\partial_t S(k, t, t') = \varepsilon_g^{k(t)} + E(t) R_{cv}^k(t) = \omega, \quad (4c)
\]

with \( R_{cv}^k = d_{cc}^k - d_{cv}^k - V_k \Phi_{cv}^k \) being the shift vector, which is combination of the Berry connections and TDPs of the conduction band and valence band. The gradient of the TDP cancels out the gauge dependence of the Berry connections, so the shift vector is gauge invariant. Eqs. (4a)-(4c) are the formulations of the semi-classical three-step model. As far as we know, the influence of the shift vector \( R_{cv}^k \) that exists in these three formulas has been overlooked so far [18,41].

The Berry connection forms the shift vector and here can be understood as the real-space charge center with quasi-momentum \( k \) in a certain band. For the system with broken inversion symmetry, the charge centers of different bands usually do not coincide. The electron wave packet subject to laser field undergoes interband transition with quasi-momentum \( k \), which appears as a hopping from one charge center to another in real space, this instantaneous process is described by the shift vector. Usually this physical quantity is given by the second-order nonlinear process under the perturbation theory [20-22]. Obviously, in a strong field, no matter how ionization and recollision happen, the process that originates from the shift vector should also exist.

We can see this process from Eqs. (4a)-(4c), which denotes a new real-space three-step model: (a) At time \( t' \), the electron that localizes in the valence band charge center (VBCC) hops to the conduction band charge center (CBCC) with the displacement \( R_{cv}^k(t') \), tunneling the combined barrier of the Coulomb potential and laser electric field, and leaving a hole in the valence band. (b) The ionized electron-hole pair is accelerated along the valence and conduction bands, respectively, by the oscillating laser field. (c) At time \( t \), the electron is pulled back from the CBCC to the VBCC by Coulomb and electric field with the displacement \( R_{cv}^k(t) \), emitting photons with energy \( \omega \) that has been modified due to the displacement. According to Eq. 4(b), the displacements of the electron and hole are exactly coincident at the moment when they recollide.
Nevertheless, we only pay attention to the directional shift when the electron tunnels, it doesn't matter here whether the electron actually recollides back with the previous hole or not [18,42].

III. THE CASE BASED ON KANE-MELE MODEL

A. Equilibrium state analysis

We further confirm the mentioned process using the KM model that hosts large shift vectors. This model is characterized by a $Z_2$ topological index that distinguishes the quantum spin Hall insulator phase from the normal insulator phase with time reversal symmetry [27]. The KM model is generalized from the tight-binding Hamiltonian of graphene with the nearest hopping term $t$, with the spin-orbit coupling (SOC) term $\lambda_{SO}$ opening a gap at the Dirac points $K$ and $K'$, and a staggered sublattice potential term $\lambda_{\nu}$ to break the inversion symmetry. The simultaneous existence of the SOC and broken inversion symmetry results in a spin splitting of bands at generic $k$-points. For simplicity, we do not consider the Rashba term $\lambda_{R}$, which can arise from an external electric field in perpendicular direction or interaction with a substrate. For such case, mirror symmetry about the $xy$ plane remains and the spin in the perpendicular direction $S_z$ remains a good quantum number, so we can decompose the KM model into two $2 \times 2$ Hamiltonians with opposite spins

$$H_{\uparrow(\downarrow)}(k) = d_1(k)\sigma_x + d_{12}(k)\sigma_y + d_2\sigma_z \pm d_{15}(k)\sigma_z,$$

where $\sigma_{x,y,z}$ is the pauli matrices, the arrows denote the spin direction, the substitutable plus and minus are specified for the spin-up and spin-down case, respectively, and

$$d_1(k) = t(1 + 2\cos(x)\cos(y)), \quad \text{(6a)}$$
$$d_{12}(k) = 2t(\cos(x)\sin(y)), \quad \text{(6b)}$$
$$d_2 = \lambda_{\nu}, \quad \text{(6c)}$$
$$d_{15} = \lambda_{SO}(2\sin(2x) - 4\sin(x)\cos(y)), \quad \text{(6d)}$$
in which $x = \frac{1}{2} a_0 k_x$, $y = \frac{\sqrt{3}}{2} a_0 k_y$, and $a_0$ is the lattice constant. As shown by the dashed line in Fig. 1(a), we take $\lambda_R = 0$, and modify $\lambda_v$ to control the topological phase transition. This system is in the normal phase (NP) when $|\lambda_v|/(3\sqrt{3} \lambda_{SO}) > 1$, and in the topological phase (TP) when $|\lambda_v|/(3\sqrt{3} \lambda_{SO}) < 1$ [Fig. 1(a)]. The bandgap closes at the critical positions where the phase transition occurs.

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As the topological phase transition approaching, the bandgap tends to close, and then the wave functions of valence and conduction bands have an exchange when the
gap closes and opens again. This is known as band inversion, which causes the shift vector composed of the wave functions to reverse in the band inversion region [Fig. 2]. Since the KM model satisfies the time reversal symmetry, the shift vector has even parity, $R_{cv,1}(k) = R_{cv,1}(-k)$ (the arrow denotes the spin direction), we only focus on the spin-down two bands, and the spin up ones are their time reversal pairs. When the transition further occurs, the peak of the shift vector moves away from the $K$ point where the band inversion starts and gradually becomes low and flat, as shown in Fig. 2. In the trivial phase, shift vector peaks around the $K$ point have abrupt reversals [Figs. 2(a) and 2(b), see the color change from red to blue along $K - K'$ path], while the sign of the peak is not changed in the topological phase [Figs. 2(c) and 2(d)].

![Image](image_url)

**FIG. 2.** Shift vectors along the $k_y$ direction (the applied laser field is in the same direction) in the first BZ (see the blue rectangle in Fig. 1(b)) of the KM model with (a) $\lambda_v/(3\sqrt{3}\lambda_{SO}) = 1.2$, (b) $\lambda_v/(3\sqrt{3}\lambda_{SO}) = 1.05$, (c) $\lambda_v/(3\sqrt{3}\lambda_{SO}) = 0.95$, and (d) $\lambda_v/(3\sqrt{3}\lambda_{SO}) = 0.8$. In the vicinity of the $K$ point, the shift vector peak is positive in the normal phase ((a), (b)) and negative in the topological phase ((c), (d)), but it is negative in all cases away from the $K$ point. The magnitude of peak is much larger than the lattice constant of the system and some prominent effects are expected.
B. Analysis of KM system in laser fields

We select two representative phase points A and B in the KM model to carry out numerical calculations over the entire BZ. As marked in Fig. 1(a), A and B points are in the NP and TP, respectively (we specify them as NP and TP points later). These two phase points own similar band structures (the same bandgap of 0.27eV) [Fig. 1(c)] and absolute values of the transition dipoles [Fig. 1(d)]. As shown in Figs. 2(a) and 2(d), the significant difference between the two phase points is the shift vector, which are opposite to each other near the bandgap due to the band inversion transition. We choose an intense mid-infrared laser polarized linearly in the direction with the wavelength \( \lambda = 6.7 \, \mu m \), the peak strength of electric field \( E_0 = 7.18 \, MV/cm \), and the full-width at half-maximum of 80 fs in a Gaussian envelope [Fig. 3(a)]. Under such laser parameters, nonadiabatic transition dominates according to Keldysh parameter \( \gamma \approx 1 \).

Figure 3(b) plots the high-harmonic spectra of the NP and TP points, and harmonics parallel to laser field are taken into consideration. A few low-order odd harmonics are well consistent due to the similar band structure [32], while some deviations can be seen in their higher order harmonics. However, more critically and essentially qualitative differences can hardly be revealed only from the high-harmonic spectra.

In order to clarify the role of the shift vector in the Topological strong-field physics [32], we focus on the HHPTs, which is integrated by the time-frequency spectrograms for each HHG order. In Figs. 3(c), 3(e) and 3(f), we can see that HHPTs emit from the NP and TP points are locked to the positive and negative laser field, respectively. We call this the tropism of HHG to the laser field. Normally, the reversal of the laser field can only cause the harmonics or currents to reverse their directions and HHG should emit every half cycle of the driving field. However, the burst periods of the sub-cycle HHPTs for both phase points are modified from half an optical cycle to a whole single cycle. This phenomenon is similar to transition of the burst cycle induced by crystal symmetry in different directions [17,44]. This suggests that the temporal fine structure of HHPTs can be resolved in experiments and the HHG tropisms of materials can be obtained. By comparing the shapes of harmonic radiation of the two phases, it can be
found that the corresponding high-order radiation (around the 30th order) of the TP point is larger than that of the NP point [Fig. 3(c)]. This is because the shift vector near the K point keeps the same sign in the TP, but reverses abruptly in the NP (Fig. 2), which can be used to distinguish the two phases.

The HHG tropism can be understood by the semi-classical saddle point analysis.
as mentioned above. Considering the time reversal invariance of the shift vector and the absolute value of transition dipole, we select the spin-down two bands to proceed calculations for the NP and TP points. The saddle point approximation results are based on Eqs. (4a)-(4c). Two distinct differences of about 10 harmonic orders are shown in Fig. 3(d). One is from the short orbit and the other is from the long orbit. Both originate from the reversal of the shift vector, because the tunneling displacement determines the change in the electron potential in the laser electric field, and the electron converts the potential change into the variation of emitted photon energy. Since the electric field is positive when the short orbit recollides, the radiated photon energy of the NP point is higher than that of the TP point. The situation is inversed when the long orbit recollides [Fig. 3(d)]. Therefore, the high-energy photons emitted from the NP and TP points are locked to the positive and negative electric field, respectively.

Here, we introduce a ratio to represent the tropism defined as

\[ T_n = \frac{I_n^+ - I_n^-}{I_n^+ + I_n^-} \]  

(7)

where \( n \) is the harmonic order, \( I_n^+ \) and \( I_n^- \) denote the intensity of the emitted photon when electric field is positive and negative, respectively.

![Fig. 4](image)

**Fig. 4.** The HHG tropisms to the laser field in the KM model system, as a function of \( \lambda_v/\lambda_{SO} \) and harmonic orders for (a) \( \lambda_{SO} = 0.06t \), and (b) \( \lambda_{SO} = 0.12t \). All the other parameters are the same. There are three sign changes in the diagrams. The middle one is from the inversion operation (black solid line). The other two are from the topological phase transitions (red solid lines). The tropism spectra of the selected NP point (red dashed line) and TP point (blue dashed line) are indicated in (a).
According to the HHG tropisms for different phases, we draw the phase transition process of the KM model (without Rashba interaction) by an all-optical strong-field method [Fig. 4]. Notice that, there is an additional sign reversal before and after the inversion symmetry approaching, because at this time the shift vector also reverses its direction due to the inversion operation. As a result, when the system undergoes the inversion operation or band inversion transition, the sign of the HHG tropism will reverse. In the vicinity of the phase transition, we can also see that the tropisms vanish for higher order harmonics, which results from that the shift vector peak is confined to the region with a small bandgap [Fig. 2]. When the SOC is doubled, we can also get a similar result in Fig. 4(b), which means that the tropism has little dependence on the strength of SOC. Here, we ignore the harmonics perpendicular to the laser field caused by the Berry curvature. Although the fact that the Berry curvature also reverses its sign as the band inversion occurs [32], it is an odd function in the BZ with time reversal symmetry, and has no practical effect on HHG as the integral of the entire BZ.

IV. THE CASE OF REAL MATERIAL: BiTeI

To illustrate the practical significance of shift vector and extend the conception to real materials with Rashba-like SOC interaction, we apply above methods and arguments to a layered polar material BiTeI [Fig. 5(a)]. The multiple layers are connected by the van der Waals interaction. Under ambient pressure, BiTeI is a normal insulator. It has a pressure-tunable bandgap located near $A$ point, the center of hexagonal like boundary surface of the BZ [Fig. 5(b)]. The system is a Weyl semimetal when the gap closes [45]. During the topological phase transition, the inversion symmetry is always broken. The bands of BiTeI have a Rashba-type splitting in the BZ except the time reversal invariant momenta [Figs. 5(c)-5(e)], which is aligned with the situation in the KM model.

Our first-principles calculations were performed by Vienna ab initio simulation package (VASP) [46] based on density functional theory. The bulk energy bands and charge density of three-dimensional BiTeI were calculated using the PBE exchange correlation functional and PAW pseudopotentials. Self-consistent calculations of the
electron density were performed on an $8 \times 8 \times 8$ Monkhorst-Pack $k$ grid with plane-wave energy cutoffs of 400 eV. To simulate the effect of pressure on the system, we kept the shape of the crystal unchanged ($a = b = 0.636c$) but adjusted its lattice constant ranging from $a = 4.42$ Å to $a = 4.02$ Å. As shown in Figs. 5(c)-5(e), the band inversion transition begins to occur when the lattice constant is around 4.22 Å and the system transforms from the NP to the TP. In virtue of Wannier90 [47] and Wannier tools packages [48], we can get the maximally localized Wannier function, which allows us to conveniently construct the dipole moment elements and shift vectors.

FIG. 5. (a) The layered crystal structure of BiTeI and its primitive cell (the black frame). (b) The corresponding Brillouin zone. The effects of changing the lattice constants that start from $a = 4.42$ Å (c,f), to $a = 4.22$ Å (d,g), to $a = 4.02$ Å (e,h). The bandgap undergoes the process of closing and reopening around the $A$ point. The orbital compositions reverse near the minimum bandgap (c-e), where the blue, yellow, green dots represent the weight from Bi-6p, Te-5p and I-5p atomic orbits in
the Bloch wave-functions, respectively. The black dashed line represents the Fermi energy. (f-h) As the band inversion occurs, the shift vector also reverses and starts at the point where the bandgap closes. In (g), the six green circles mark three pairs of weyl points along the $A - H$ direction where the bandgap closing occurs.

Figures 5(f)-5(h) show shift vectors along the $k_x$ direction (the applied laser field is in the same direction) on the $LAH$ surface between the lowest conduction band and the highest valence band. The shift vector is invariant under the time reversal operation and the mirror reflection operation about $\Gamma AH$ plane perpendicular to the shift vector, which can be reflected in the Figs. 5(f)-5(h). Figures 5(c)-5(h) manifest the reversal of the shift vector that results from the band inversion.

FIG. 6. The HHG tropisms to the laser field in BiTeI with different lattice constants. Two lowest conduction bands and two highest valence bands with Rashba splitting are considered for the calculations. Both the laser and nonlinear effect that we focus on are oriented along the $k_x$ direction. The diagrams of the NP and TP are drawn by lines with circles and diamonds, respectively. The two phases can be directly distinguished by signs of the tropisms. We do not plot the case near the phase transition, because the band inversion region and the bandgap are too small to cause harmonics to show significant tropism.

Finally, we draw the tropisms of harmonics from BiTeI in a strong laser field. Since we only focus on low energy excitation near the Fermi energy, the laser of wavelength $\lambda = 15.6 \mu m$ and peak strength $E_0 = 1.54 MV/cm$ are used. For simplicity, we only consider the HHG contributes from the $LAH$ surface in the BZ, a $300 \times 300$ meshy $k$-point sample over the surface is chosen to proceed the time dependent evolution. From Fig. 6, we can see that there is an obvious sign reverse between different phases. The spectral lines are positive in the NP, and negative in the
We present the tropism for twenty harmonic orders (1st to 20th) due to the harmonic cutoffs are around the 20th order. The magnitude and position of the spectral peaks are related to their corresponding shift vectors and band structure. As the bandgap increases, the peak position moves to the higher order region and the peak value tends to the limit of value 1 or –1 for tropism as defined. Consequently, the strong field nonlinear optical effect brought by the band inversion is very clear. This signifies that it is promising to detect the process of band inversion and topological phase transition of non-centrosymmetric materials by means of an ultrafast strong laser all-optical method.

V. CONCLUDING REMARKS

In conclusion, our work improves the electron tunneling picture driven by a strong laser in real space, and revealed the key role of the shift vector in solid HHG from non-centrosymmetric systems. We find that HHPTs display novel phenomena due to the inversion symmetry breaking. Benefited from the fact that the band inversion causes the shift vector reversing, we propose an all-optical method to characterize the band inversion during the phase transition in non-centrosymmetric TIs. Fortunately, it is experimentally feasible that a nonlinear cross-correlation measurement using an ultrashort gating pulse to scan the HHG with a time delay is able to retrieval the HHPTs [17,44]. In addition to the phenomena mentioned above, we consider the shift vector should also play a role in the even order harmonic generation and broaden the harmonics cutoff. Besides the TIs, it is expected to apply our conception to search for the Weyl semimetals without inversion centers [45] and materials with large shift current [24]. Throughout this work, only the linearly polarized light is considered, while it is further expected to exploit new strong-field nonlinear phenomena under circularly polarized light combined with topological geometry[25,33,49]. The injection current from the weak field generated by a sudden change in electron velocity is also instructive [49,50].
ACKNOWLEDGMENT

C. Q. thanks Yuting Qian, Guanlu Yuan, Tong Wu, and Xiangyu Tang for their help in the early exploration stage. This work was supported by NSF of China (11974185, 11704187, 11834004, 11925408, 11921004), the Natural Science Foundation of Jiangsu Province (Grant No. BK20170032), Fundamental Research Funds for the Central Universities (No. 30920021153), the Project funded by China Postdoctoral Science Foundation (Grant No. 2019M661841), the National Key Research and Development Program of China (2018YFA0305700), the Strategic Priority Research Program of CAS (XDB33000000), and the K. C. Wong Education Foundation (Grant No. GJTD-2018-01).

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